



UTT50N06

Power MOSFET

50A, 60V N-CHANNEL POWER MOSFET

DESCRIPTION

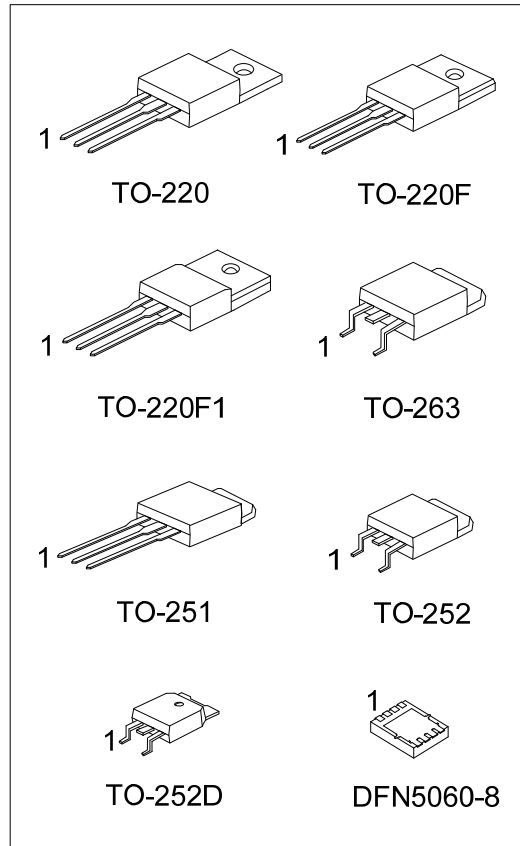
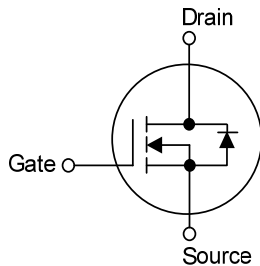
The UTC **UTT50N06** is an N-channel power MOSFET using UTC's advanced technology to provide customers with a minimum on-state resistance and superior switching performance.

The UTC **UTT50N06** is generally applied in low power switching mode power appliances and electronic ballast.

FEATURES

- * $R_{DS(ON)} \leq 20m\Omega @ V_{GS}=10V, I_D=25A$
- * High Switching Speed
- * Improved dv/dt capability

SYMBOL



ORDERING INFORMATION

Ordering Number		Package	Pin Assignment								Packing	
Lead Free	Halogen Free		1	2	3	4	5	6	7	8		
UTT50N06L-TA3-T	UTT50N06G-TA3-T	TO-220	G	D	S	-	-	-	-	-	-	Tube
UTT50N06L-TF3-T	UTT50N06G-TF3-T	TO-220F	G	D	S	-	-	-	-	-	-	Tube
UTT50N06L-TF1-T	UTT50N06G-TF1-T	TO-220F1	G	D	S	-	-	-	-	-	-	Tube
UTT50N06L-TM3-T	UTT50N06G-TM3-T	TO-251	G	D	S	-	-	-	-	-	-	Tube
UTT50N06L-TN3-R	UTT50N06G-TN3-R	TO-252	G	D	S	-	-	-	-	-	-	Tape Reel
UTT50N06L-TND-R	UTT50N06G-TND-R	TO-252D	G	D	S	-	-	-	-	-	-	Tape Reel
UTT50N06L-TQ2-T	UTT50N06G-TQ2-T	TO-263	G	D	S	-	-	-	-	-	-	Tube
UTT50N06L-TQ2-R	UTT50N06G-TQ2-R	TO-263	G	D	S	-	-	-	-	-	-	Tape Reel
UTT50N06L-K08-5060-R	UTT50N06G-K08-5060-R	DFN5060-8	S	S	S	G	D	D	D	D	D	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

<p>UTT50N06G-TA3-T</p> <p>(1)Packing Type</p> <p>(2)Package Type</p> <p>(3)Green Package</p>	<p>(1) T: Tube, R: Tape Reel</p> <p>(2) TA3: TO-220, TF3: TO-220F, TF1: TO-220F1</p> <p>TM3: TO-251, TN3: TO-252, TND: TO-252D,</p> <p>TQ2: TO-263, K08-5060: DFN5060-8</p> <p>(3) G: Halogen Free and Lead Free, L: Lead Free</p>
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MARKING

TO-220 / TO-220F / TO-220F1 / TO-251 TO-252 / TO-252D / TO-263	DFN5060-8
<p>UTC UTT50N06 □ □□□□ □ → L: Lead Free → G: Halogen Free Lot Code ← □□□□ □ → Date Code 1</p>	<p>UTC UTT50N06 □ □□□□ □ → L: Lead Free → G: Halogen Free Lot Code ← □□□□ □ → Date Code •</p>

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■ ABSOLUTE MAXIMUM RATINGS ((T_C=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V _{DSS}	60	V
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current		I _D	50	A
Pulsed Drain Current (Note 2)		I _{DM}	150	A
Avalanche Energy	Single Pulsed (Note 3)	E _{AS}	92	mJ
Peak Diode Recovery dv/dt		dv/dt	10	V/ns
Power Dissipation	TO-220/TO-263	P _D	100	W
	TO-220F/TO-220F1		36	W
	TO-251/TO-252		46	W
	TO-252D			
	DFN5060-8		20.8	W
Junction Temperature		T _J	+150	°C
Operation and Storage Temperature		T _{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating : Pulse width limited by maximum junction temperature.

3. L=43mH, I_{AS}=43A, V_{DD}=25V, R_C=20Ω, Starting T_J=25°C

4. I_{SD} ≤ 30A, V_{DS}=0V, di/dt ≤ 200A/μs, V_{DD} ≤ BV_{DSS}, Starting T_J = 25°C

■ THERMAL DATA

PARAMETER		SYMBOL	RATING	UNIT
Junction to Ambient	TO-220/TO-220F	θ _{JA}	62	°C/W
	TO-220F1/TO-263			
	TO-251/TO-252		100	°C/W
	TO-252D			
	DFN5060-8		65	°C/W
Junction to Case	TO-220/TO-263	θ _{JC}	1.24	°C/W
	TO-220F/TO-220F1		3.47	°C/W
	TO-251/TO-252		2.7 (Note)	°C/W
	TO-252D			
			DFN5060-8	6 (Note)

Note: The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.

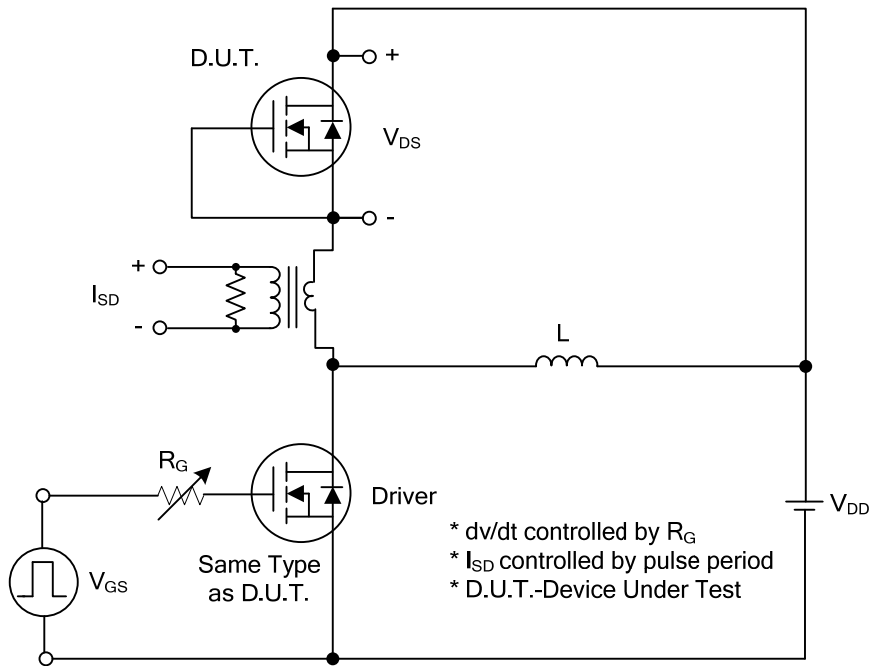
■ ELECTRICAL CHARACTERISTICS (T_J= 25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250μA	60			V
Drain-Source Leakage Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V			10	μA
Gate-Source Leakage Current	Forward	I _{GSS}			100	nA
	Reverse					
		V _{GS} =-20V, V _{DS} =0V			-100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	V _{DS} =V _{GS} , I _D =250μA	1.0		3.0	V
Static Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =25A			20	mΩ
DYNAMIC CHARACTERISTICS						
Input Capacitance	C _{ISS}	V _{GS} =0V, V _{DS} =25V, f=1MHz		2500		pF
Output Capacitance	C _{OSS}			230		pF
Reverse Transfer Capacitance	C _{RSS}			200		pF
SWITCHING CHARACTERISTICS						
Total Gate Charge	Q _G	V _{DS} =50V, V _{GS} =10V, I _D =1.3A I _G =3mA (Note1,2)		7.2		nC
Gate-Source Charge	Q _{GS}			0.4		nC
Gate-Drain Charge	Q _{GD}			0.8		nC
Turn-On Delay Time	t _{D(ON)}	V _{DS} =30V, V _{GS} =10V, I _D =50A, R _G =25Ω (Note1,2)		18		ns
Turn-On Rise Time	t _R			46		ns
Turn-Off Delay Time	t _{D(OFF)}			202		ns
Turn-Off Fall Time	t _F			116		ns
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS						
Maximum Continuous Drain-Source Diode Forward Current	I _S				50	A
Maximum Pulsed Drain-Source Diode Forward Current	I _{SM}				150	A
Drain-Source Diode Forward Voltage	V _{SD}	I _S =50A, V _{GS} =0V			1.5	V
Body Diode Reverse Recovery Time	t _{rr}	I _S =30A, V _{GS} =0V,		50		ns
Body Diode Reverse Recovery Charge	Q _{rr}	dI _S /dt=100A/μs		80		nC

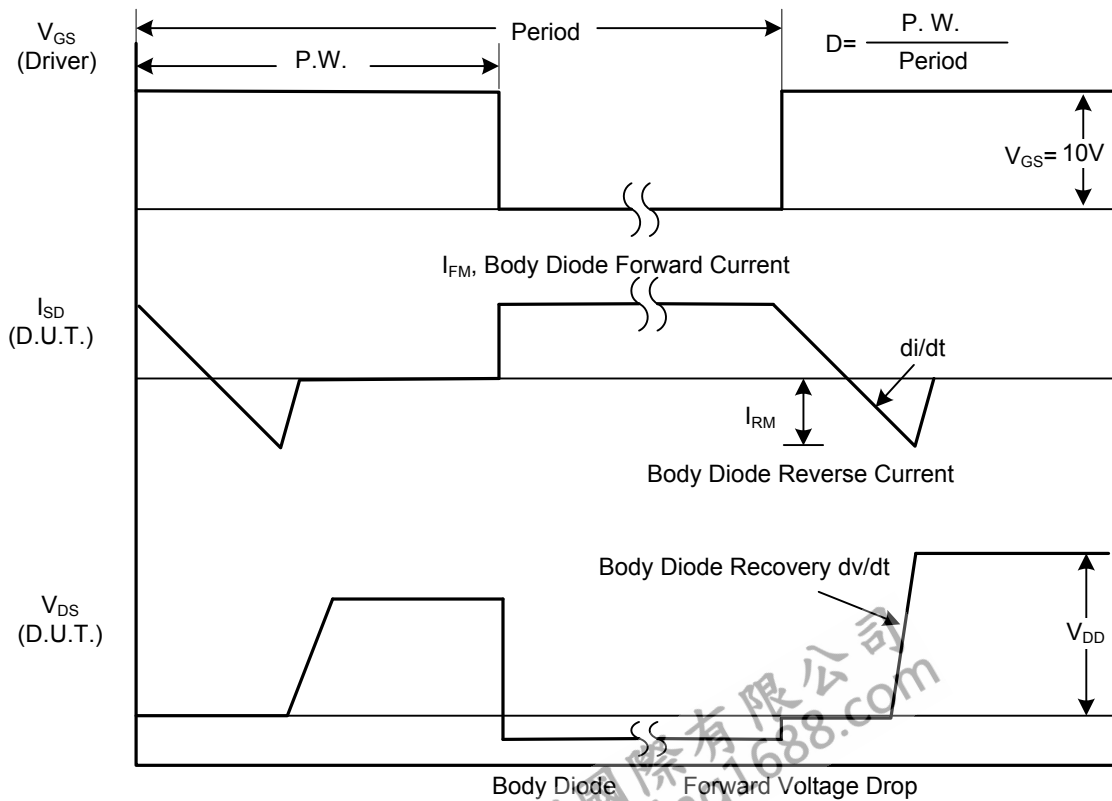
Notes: 1. Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.

2. Essentially independent of operating temperature.

■ TEST CIRCUITS AND WAVEFORMS



Peak Diode Recovery dv/dt Test Circuit



Peak Diode Recovery dv/dt Waveforms

■ TEST CIRCUITS AND WAVEFORMS

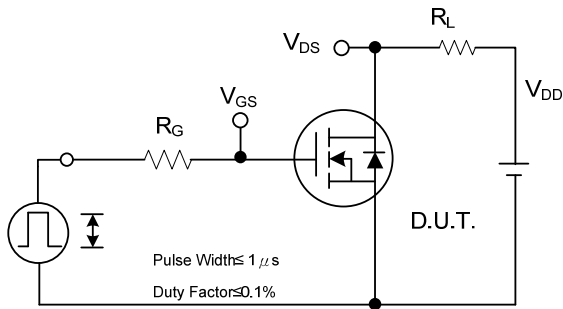


Fig. 2A Switching Test Circuit

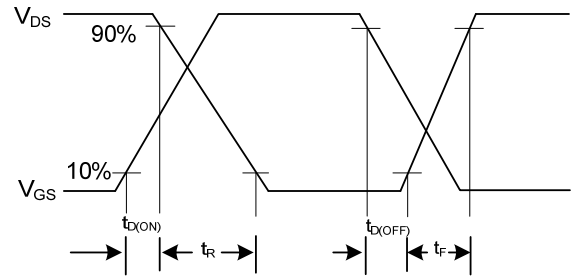


Fig. 2B Switching Waveforms

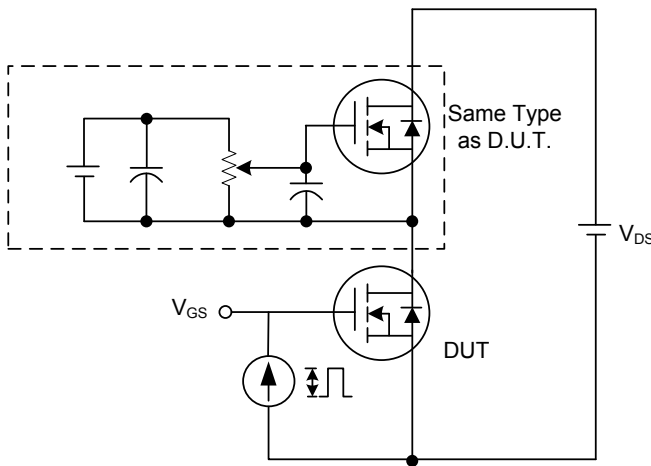


Fig. 3A Gate Charge Test Circuit

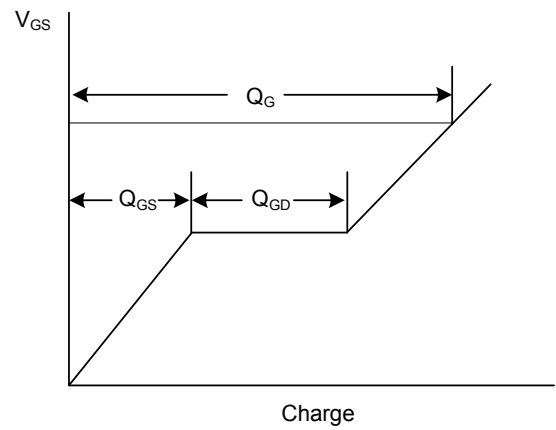


Fig. 3B Gate Charge Waveform

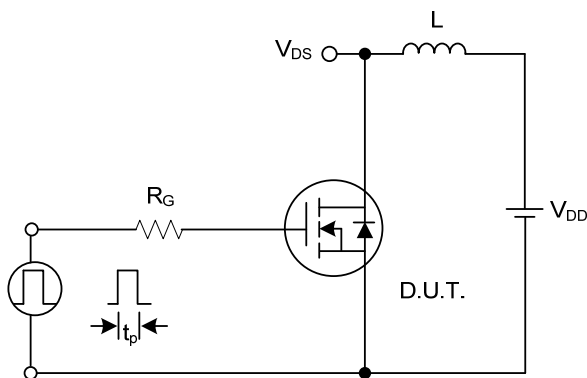


Fig. 4A Unclamped Inductive Switching Test Circuit

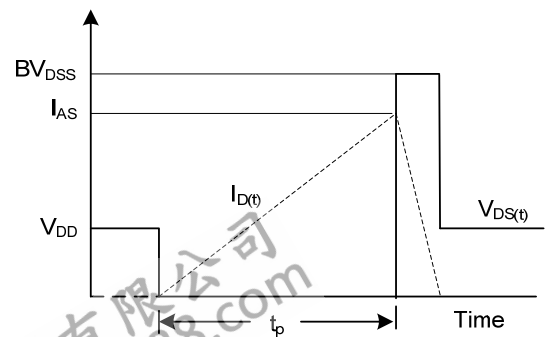
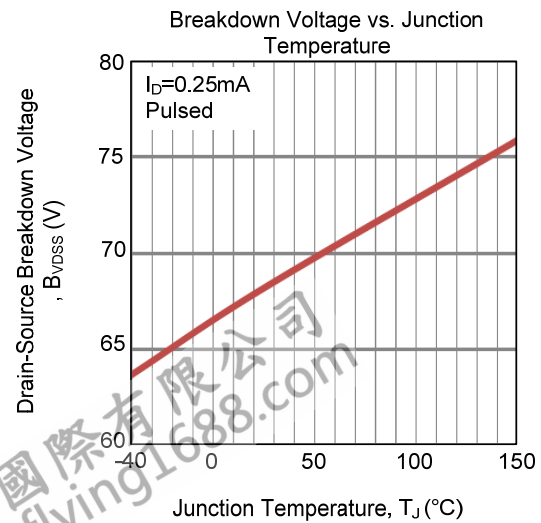
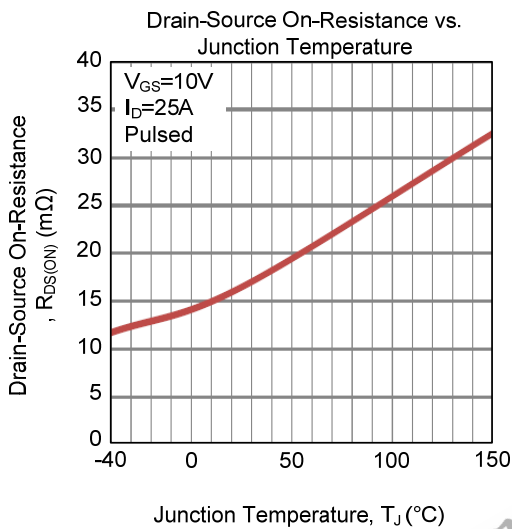
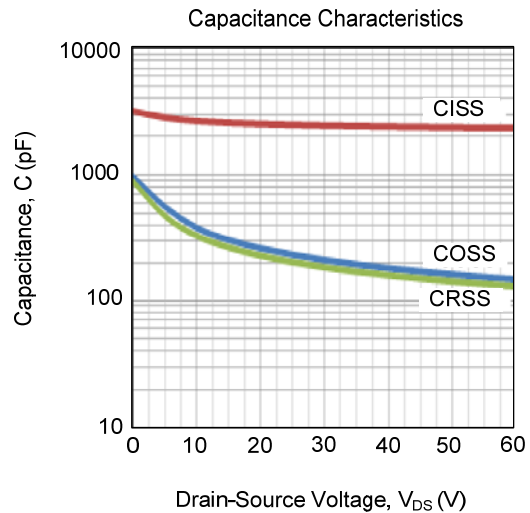
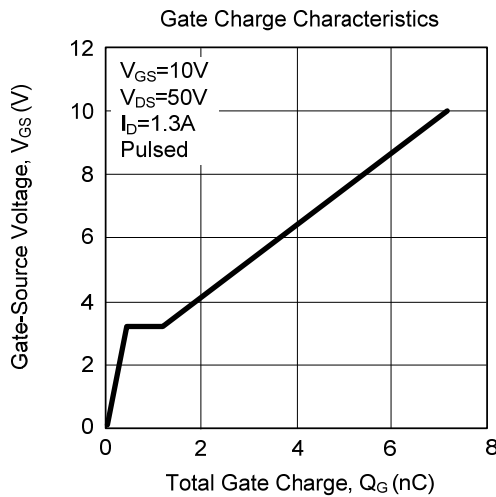
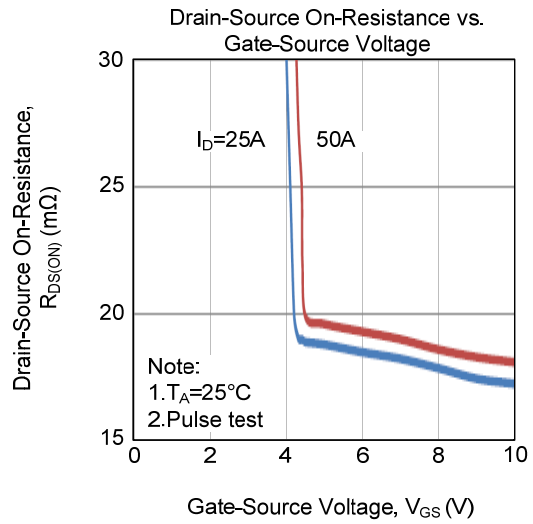
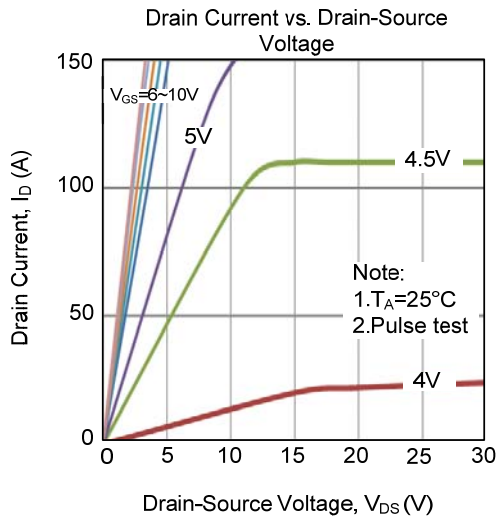
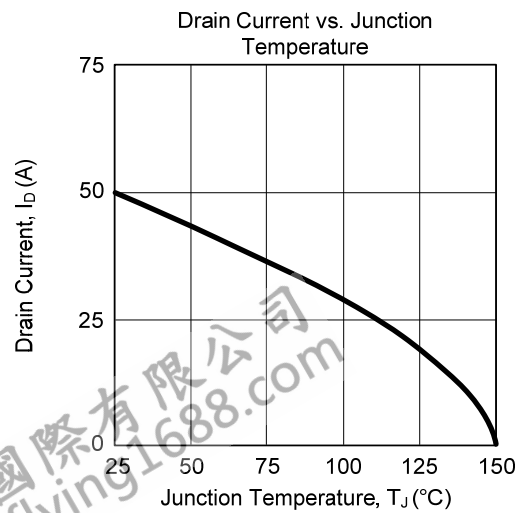
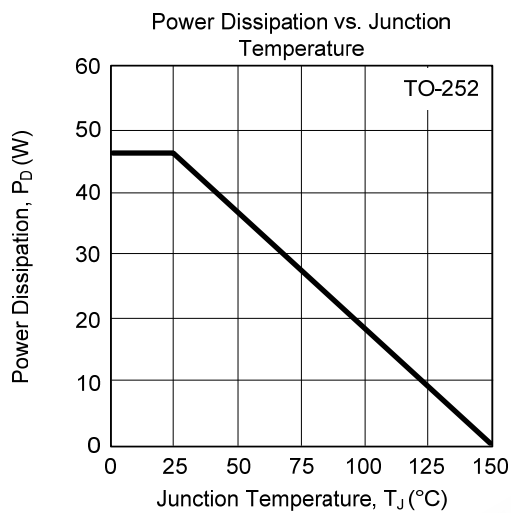
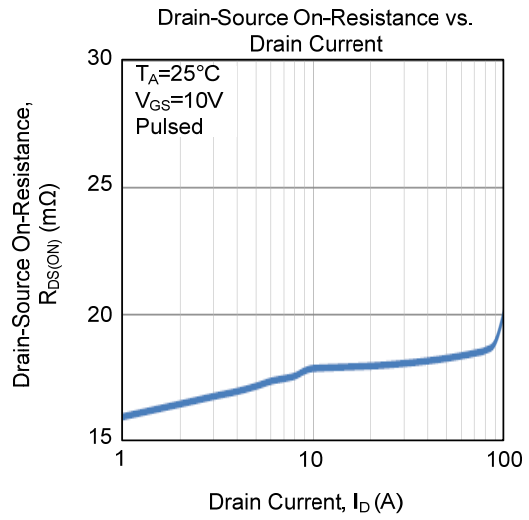
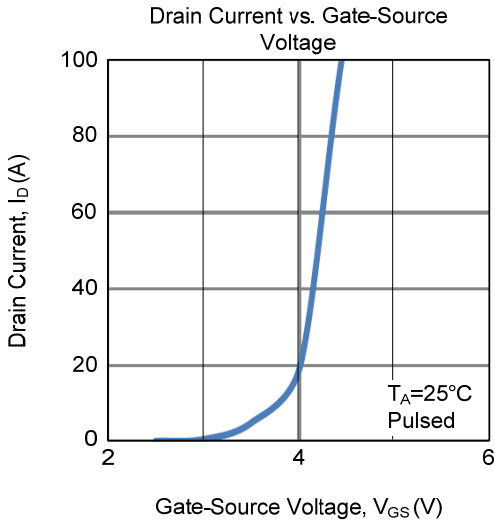
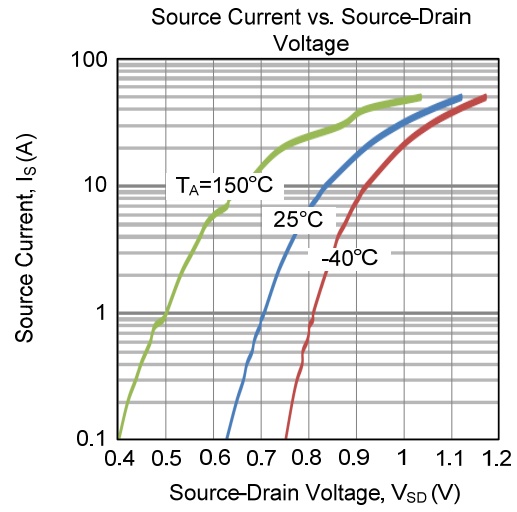
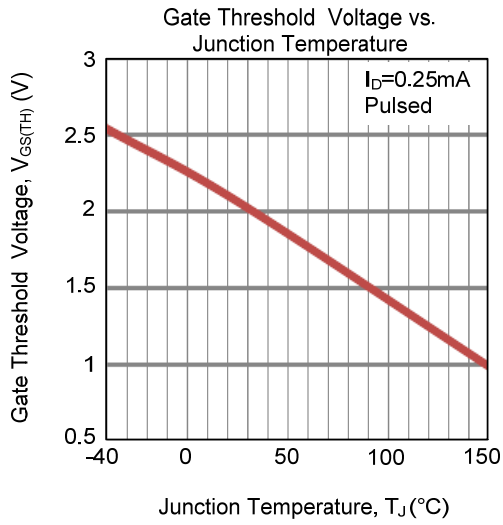


Fig. 4B Unclamped Inductive Switching Waveforms

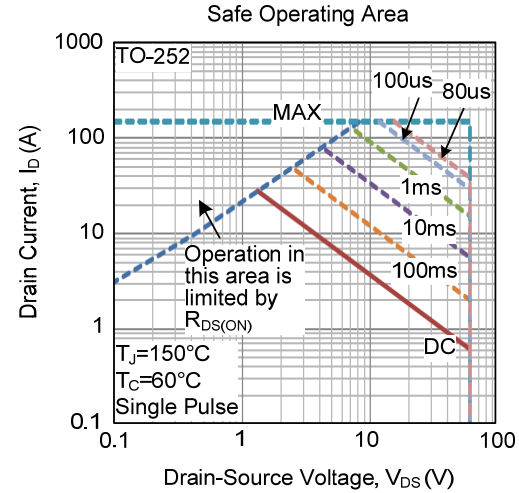
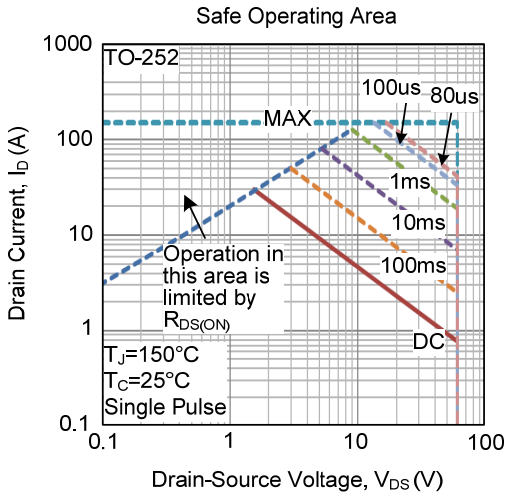
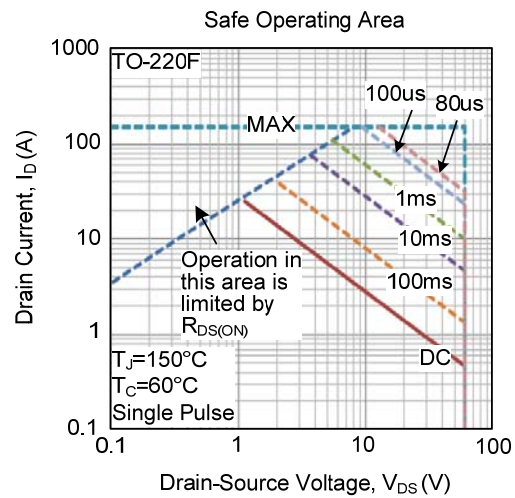
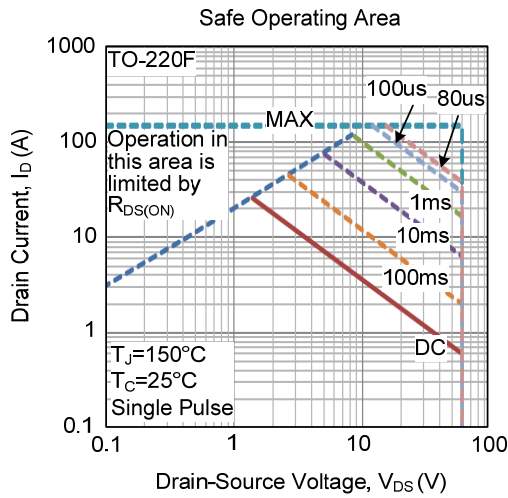
TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS (Cont.)



■ TYPICAL CHARACTERISTICS (Cont.)



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